

## PAPER

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13588Mixed-anion chalcogenide-halide semiconductors  
 $A_2BaTaS_4Cl$  ( $A = K, Rb, Cs$ ) and  $K_2BaNbS_4Cl$ Thomas S. Ie,<sup>a</sup> Siddhartha S. Nathan,<sup>b</sup> James M. Rondinelli<sup>b</sup> and  
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Four mixed-anion materials,  $K_2BaTaS_4Cl$ ,  $Rb_2BaTaS_4Cl$ ,  $Cs_2BaTaS_4Cl$  and  $K_2BaNbS_4Cl$  were synthesized via low temperature solid state synthesis at 848 K. All materials degrade upon melting to a mixture of the binary ionic salts,  $ACl$ , and  $ABaMS_4$ , two of which ( $KBaTaS_4$  and  $CsBaTaS_4$ ) are reported here for the first time. Single crystal X-ray diffraction revealed that  $K_2BaTaS_4Cl$ ,  $Rb_2BaTaS_4Cl$ , and  $K_2BaNbS_4Cl$  crystallize in the tetragonal space group  $I4/mcm$ , adopting the  $Cs_3CoCl_5$  structure type. In this phase, isolated  $[MS_4]^{3-}$  tetrahedra are encapsulated within a  $(K, Rb)/Ba-Cl$  ionic cage. Although structurally similar,  $Cs_2BaTaS_4Cl$  crystallizes in the orthorhombic space group  $Ibam$ , arising from a supercell with a  $\sqrt{2}$  expansion along the  $a$ -axis and a  $2\sqrt{2}$  expansion along the  $b$ -axis due to extended  $Cs$  and  $Ba$  ordering. Consistent with electronic structure calculations, the measured bandgaps of the  $Ta$ -based compounds are  $\sim 3.0$  eV while the  $Nb$ -based compounds exhibit a reduced bandgap of  $\sim 2.5$  eV, reflecting the lower energy of the  $Nb$  d orbitals.

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## 1. Introduction

Mixed-anion or heteroanionic compounds, materials that contain more than one type of anion within a single structure, with each anion exhibiting some degree of long-range ordering, represent a particularly promising class of materials. The presence of multiple distinct anions enables access to properties that are typically unattainable in single-anion systems.<sup>1–8</sup> These properties include tunable bandgaps and crystal field splitting, reduced dimensionality, disrupted local symmetry, and enhanced structural diversity arising from unique bonding motifs enabled by the inclusion of multiple anionic species.<sup>3–11</sup> Owing to these characteristics, heteroanionic materials have attracted interest across a wide range of research fields, including thermoelectrics, photocatalysis, and nonlinear optics.<sup>4,9,12–15</sup> The presence of multiple anions, however, also complicates the synthesis of novel heteroanionic compounds.<sup>8,16</sup> Although the number of potential compounds should theoretically increase exponentially, only a limited number have been reported to date. Consequently, the discovery of new heteroanionic materials often relies on more targeted approaches, such as compositional tuning within known compound families.

One particularly promising family for such tuning is  $Ba_3MQ_4X$  ( $M = Fe, Al, Ga, In$ ;  $Q = S, Se$ ;  $X = Cl, Br, I$ ). These compounds exhibit significant structural flexibility, owing to their ability to accommodate various combinations of metals, chalcogens, and halides.<sup>17</sup> Depending on the specific elemental radius ratios, members of this family can adopt several distinct structure types, including the  $Ba_3GaS_4Cl$ -type structure ( $Pnma$ ),<sup>17–21</sup> the  $Cs_3CoCl_5/K_3SO_4F$ -type structure ( $I4/mcm$ ),<sup>17,19,22</sup> or in the case of  $Ba_3GaS_4I$ , a unique structure type ( $Cmcm$ ).<sup>23</sup> Further compositional tuning has even been achieved by substituting  $Ba^{2+}$  with a monovalent alkali metal, allowing for the design of new compounds with tetravalent metals such as  $Ge$  or  $Sn$ , resulting in the general formula  $ABa_2MQ_4X$  ( $A = Na, K, Rb, Cs$ ;  $M = Ge, Sn$ ;  $Q = S, Se$ ;  $X = Cl, Br, I$ ).<sup>24,25</sup> This substitution not only expands the range of accessible materials but also allows for structural tuning based on the size of the alkali cation. This trend is illustrated in the  $ABa_2SnS_4X$  ( $A = Na, K, Rb, Cs$ ) system.  $NaBa_2SnS_4Cl$  and  $KBa_2SnS_4Cl$  crystallize in the aforementioned  $Cs_3CoCl_5/K_3SO_4F$ -type structure type. However, as the size of the alkali metal increases,  $RbBa_2SnS_4Cl$  and  $CsBa_2SnS_4Cl$  adopt a distorted structure due to changes in the  $Rb/Cs$  and  $Ba$  coordination environments, resulting in a monoclinic  $P2_1/c$  space group.<sup>24,26</sup>

Building on these findings, a logical extension involves substituting a second  $Ba^{2+}$  ion with a monovalent alkali metal, thereby enabling the stabilization of compounds containing pentavalent metals such as  $V, Nb$ , or  $Ta$ . This approach can be generalized using the composition  $A_xBa_{3-x}M^{III+x}Q_4X$ , encom-

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passing a wide range of potential combinations. In this work, we demonstrate the feasibility of this strategy through the synthesis of four new mixed-anion materials,  $A_2BaTaS_4Cl$  ( $A = K, Rb, Cs$ ) and  $K_2BaNbS_4Cl$ , as well as two additional single-anion compounds,  $ABaTaS_4$  ( $A = K, Cs$ ). We report their synthesis and characterization, focusing on phase stability, optical responses, and crystal structures, and how variations in the alkali metal component influence these properties.

## 2. Experimental section

### 2.1. Synthesis

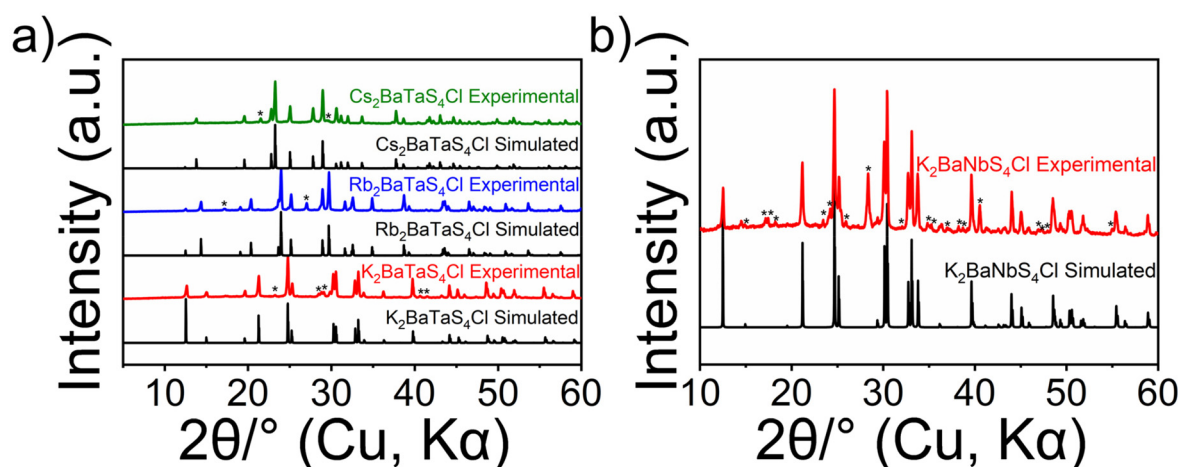
Bulk  $A_2Ba(Nb,Ta)S_4Cl$  were synthesized at a 2 g scale by combining  $A_2S_x$ , BaS, ACl, Nb/Ta, and S in a stoichiometric ratio. Materials were homogenized using a mortar and pestle while inside an  $N_2$ -filled glovebox and subsequently charged into an aluminum-lined carbon-coated fused silica tube (12.7 mm OD, 10.5 mm ID). All tubes were lined with aluminum foil to minimize powder-coating the inside walls of the tubes. The foil liner was then removed, and the tubes were taken from the glovebox and evacuated on a vacuum line to  $\sim 3 \times 10^{-3}$  mbar. The tubes were subsequently flame-sealed using an oxygen-methane torch. The sealed tube was placed inside a one-zone programmable tube furnace packed with insulation wool. The furnace was heated to 575 °C at a rate of  $\sim 45$  °C  $h^{-1}$  and left to dwell for 24 hours. The furnace was then cooled to room temperature at a rate of 10 °C  $h^{-1}$ . All tubes were opened inside an  $N_2$ -filled glovebox showing orange-yellow powders for all compounds. The ingots were then ground into powders and then washed using anhydrous dimethylformamide (DMF) to remove excess  $A_2S_x$  resulting in a whitish yellow powder for  $K_2BaTaS_4Cl$ ,  $Rb_2BaTaS_4Cl$ , and  $Cs_2BaTaS_4Cl$  and bright yellow powder for  $K_2BaNbS_4Cl$ . PXRD on all materials confirmed the phase formation alongside minor secondary phases for each compound (Fig. 1).

### 2.2. Single crystal growth

Single crystals of  $A_2BaMS_4Cl$  and  $ABaTaS_4$  were synthesized at a 1 g scale by combining  $A_2S_x$ , BaS, ACl, Ta/Nb, and S in stoichiometric ratios. Materials were homogenized using a mortar and pestle while inside an  $N_2$ -filled glovebox and subsequently charged into an aluminum-lined carbon coated fused silica tube (9 mm OD, 7 mm ID). All tubes were lined with aluminum foil to minimize powder-coating the inside walls of the tubes. The foil liner was then removed, and the tubes were taken from the glovebox and evacuated on a vacuum line to  $\sim 3 \times 10^{-3}$  mbar. The tubes were subsequently flame-sealed using an oxygen-methane torch. The sealed tube was placed inside a one-zone programmable tube furnace packed with insulation wool. The furnace was heated to 750 °C at a rate of  $\sim 60$  °C  $h^{-1}$  and left to dwell for 24 hours. The furnace was then cooled to room temperature at a rate of 10 °C  $h^{-1}$ . All tubes were opened inside an  $N_2$ -filled glovebox showing yellow to clear single crystals for all samples. Powder X-ray Diffraction (PXRD) and single crystal analysis revealed products to be a mix of  $A_2BaTaS_4Cl$ ,  $ABaTaS_4$ , and ACl ( $A = K, Rb, Cs$ ) (Table 1 and Tables S1–7). Single crystals were then isolated from reaction without washing.

### 2.3. Single crystal X-ray diffraction (SCXRD)

For the acquisition of intensity data, suitable single crystals were mounted on a loop with paratone oil and mounted onto a XtaLAB Synergy Diffractometer. The XtaLAB Synergy diffractometer was equipped with a microfocus-sealed X-ray tube PhotonJet (Mo) X-ray source and a Hybrid Pixel Array Detector (HyPix). The temperature of the crystals was controlled with an Oxford Cryosystems 700 series low-temperature device. Data reduction was performed with the CrysAlisPro software (Rigaku) using an empirical and numerical absorption correction. All structures were solved with the ShelXT<sup>27</sup> structure solution program using the intrinsic phasing solution method



**Fig. 1** PXRDs of (a)  $K_2BaTaS_4Cl$ ,  $Rb_2BaTaS_4Cl$ , and  $Cs_2BaTaS_4Cl$  and (b)  $K_2BaNbS_4Cl$  when compared to their simulated patterns. Secondary phases are highlighted using stars, which are primarily composed of the alkali metal salts (KCl, RbCl, CsCl) and their single anion counterparts  $ABaMS_4$  ( $A = K, Rb, Cs$ ;  $M = Nb, Ta$ ).



**Table 1** Crystallographic data and structure refinement of K<sub>2</sub>BaNbS<sub>4</sub>Cl and A<sub>2</sub>BaTaS<sub>4</sub>Cl (A = K, Rb, Cs)

| Empirical formula                                            | K <sub>2</sub> BaNbS <sub>4</sub> Cl                                                                                       | K <sub>2</sub> BaTaS <sub>4</sub> Cl                                                                                       | Rb <sub>2</sub> BaTaS <sub>4</sub> Cl                                                                                      | Cs <sub>2</sub> BaTaS <sub>4</sub> Cl                                                                                        |
|--------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------|
| Formula weight                                               | 472.14                                                                                                                     | 560.18                                                                                                                     | 652.92                                                                                                                     | 747.80                                                                                                                       |
| Temperature                                                  | 278.5(7) K                                                                                                                 | 297.15(10) K                                                                                                               | 275(1) K                                                                                                                   | 101(2) K                                                                                                                     |
| Wavelength                                                   | 0.71073 Å                                                                                                                  | 0.71073 Å                                                                                                                  | 0.71073 Å                                                                                                                  | 0.71073 Å                                                                                                                    |
| Crystal system                                               | Tetragonal                                                                                                                 | Tetragonal                                                                                                                 | Tetragonal                                                                                                                 | Orthorhombic                                                                                                                 |
| Space group                                                  | <i>I4/mcm</i>                                                                                                              | <i>I4/mcm</i>                                                                                                              | <i>I4/mcm</i>                                                                                                              | <i>Ibam</i>                                                                                                                  |
| Unit cell dimensions                                         | <i>a</i> = 8.3800(2) Å, $\alpha$ = 90°<br><i>b</i> = 8.3800(2) Å, $\beta$ = 90°<br><i>c</i> = 14.1605(4) Å, $\gamma$ = 90° | <i>a</i> = 8.3480(2) Å, $\alpha$ = 90°<br><i>b</i> = 8.3480(2) Å, $\beta$ = 90°<br><i>c</i> = 14.1063(4) Å, $\gamma$ = 90° | <i>a</i> = 8.7216(2) Å, $\alpha$ = 90°<br><i>b</i> = 8.7216(2) Å, $\beta$ = 90°<br><i>c</i> = 14.1546(6) Å, $\gamma$ = 90° | <i>a</i> = 12.7216(2) Å, $\alpha$ = 90°<br><i>b</i> = 25.4311(4) Å, $\beta$ = 90°<br><i>c</i> = 14.1934(3) Å, $\gamma$ = 90° |
| Volume                                                       | 994.41(6) Å <sup>3</sup>                                                                                                   | 983.06(5) Å <sup>3</sup>                                                                                                   | 1076.69(7) Å <sup>3</sup>                                                                                                  | 4591.91(14) Å <sup>3</sup>                                                                                                   |
| Z                                                            | 4                                                                                                                          | 4                                                                                                                          | 4                                                                                                                          | 16                                                                                                                           |
| Density (calculated)                                         | 3.154 g cm <sup>-3</sup>                                                                                                   | 3.785 g cm <sup>-3</sup>                                                                                                   | 4.028 g cm <sup>-3</sup>                                                                                                   | 4.327 g cm <sup>-3</sup>                                                                                                     |
| Absorption coefficient                                       | 6.953 mm <sup>-1</sup>                                                                                                     | 16.990 mm <sup>-1</sup>                                                                                                    | 23.723 mm <sup>-1</sup>                                                                                                    | 20.076 mm <sup>-1</sup>                                                                                                      |
| <i>F</i> (000)                                               | 864                                                                                                                        | 992                                                                                                                        | 1136                                                                                                                       | 5120                                                                                                                         |
| Crystal size                                                 | 0.28 × 0.21 × 0.14 mm <sup>3</sup>                                                                                         | 0.27 × 0.21 × 0.04 mm <sup>3</sup>                                                                                         | 0.189 × 0.138 × 0.073 mm <sup>3</sup>                                                                                      | 0.072 × 0.052 × 0.024 mm <sup>3</sup>                                                                                        |
| $\theta$ range for data collection                           | 2.877 to 33.723°                                                                                                           | 2.888 to 33.560°                                                                                                           | 2.878 to 33.766°                                                                                                           | 2.681 to 33.614°                                                                                                             |
| Index ranges                                                 | −13 ≤ <i>h</i> ≤ 12, −11 ≤ <i>k</i> ≤ 12,<br>−21 ≤ <i>l</i> ≤ 18                                                           | −12 ≤ <i>h</i> ≤ 11, −12 ≤ <i>k</i> ≤ 11,<br>−21 ≤ <i>l</i> ≤ 20                                                           | −13 ≤ <i>h</i> ≤ 12, −9 ≤ <i>k</i> ≤ 12,<br>−20 ≤ <i>l</i> ≤ 20                                                            | −18 ≤ <i>h</i> ≤ 19, −38 ≤ <i>k</i> ≤ 36,<br>−13 ≤ <i>l</i> ≤ 20                                                             |
| Reflections collected                                        | 7562                                                                                                                       | 7530                                                                                                                       | 4928                                                                                                                       | 38 084                                                                                                                       |
| Independent reflections                                      | 525 [ <i>R</i> <sub>int</sub> = 0.0305]                                                                                    | 518 [ <i>R</i> <sub>int</sub> = 0.0360]                                                                                    | 553 [ <i>R</i> <sub>int</sub> = 0.0222]                                                                                    | 4277 [ <i>R</i> <sub>int</sub> = 0.0325]                                                                                     |
| Completeness to $\theta$ = 25.242°                           | 100%                                                                                                                       | 100%                                                                                                                       | 100%                                                                                                                       | 99.8%                                                                                                                        |
| Refinement method                                            | Full-matrix least-squares on <i>F</i> <sup>2</sup>                                                                         | Full-matrix least-squares on <i>F</i> <sup>2</sup>                                                                         | Full-matrix least-squares on <i>F</i> <sup>2</sup>                                                                         | Full-matrix least-squares on <i>F</i> <sup>2</sup>                                                                           |
| Data/restraints/parameters                                   | 525/1/20                                                                                                                   | 518/0/18                                                                                                                   | 553/0/18                                                                                                                   | 4277/0/96                                                                                                                    |
| Goodness-of-fit                                              | 1.152                                                                                                                      | 1.144                                                                                                                      | 1.112                                                                                                                      | 1.047                                                                                                                        |
| Final <i>R</i> indices [ <i>I</i> > 2 $\sigma$ ( <i>I</i> )] | <i>R</i> <sub>obs</sub> = 0.0139, <i>wR</i> <sub>obs</sub> = 0.0306                                                        | <i>R</i> <sub>obs</sub> = 0.0177, <i>wR</i> <sub>obs</sub> = 0.0483                                                        | <i>R</i> <sub>obs</sub> = 0.0156, <i>wR</i> <sub>obs</sub> = 0.0310                                                        | <i>R</i> <sub>obs</sub> = 0.0229, <i>wR</i> <sub>obs</sub> = 0.0585                                                          |
| <i>R</i> indices [all data]                                  | <i>R</i> <sub>all</sub> = 0.0155, <i>wR</i> <sub>all</sub> = 0.0311                                                        | <i>R</i> <sub>all</sub> = 0.0204, <i>wR</i> <sub>all</sub> = 0.0495                                                        | <i>R</i> <sub>all</sub> = 0.0184, <i>wR</i> <sub>all</sub> = 0.0315                                                        | <i>R</i> <sub>all</sub> = 0.0292, <i>wR</i> <sub>all</sub> = 0.0611                                                          |
| Extinction coefficient                                       | 0.00456(16)                                                                                                                | 0.00188(15)                                                                                                                | 0.00081(5)                                                                                                                 | N/A                                                                                                                          |
| Largest diff. peak and hole                                  | 0.390 and −0.336 e Å <sup>-3</sup>                                                                                         | 0.780 and −2.046 e Å <sup>-3</sup>                                                                                         | 0.625 and −0.596 e Å <sup>-3</sup>                                                                                         | 5.165 and −1.871 e Å <sup>-3</sup>                                                                                           |

$$R = \sum ||F_o| - |F_c|| / \sum |F_o|, wR = \{ \sum [w(|F_o|^2 - |F_c|^2)^2] / \sum [w(|F_o|^4)] \}^{1/2} \text{ and } w = 1 / [\sigma^2(F_o^2) + (0.0094P)^2 + 3.4287P] \text{ where } P = (F_o^2 + 2F_c^2)/3.$$

and by using Olex2<sup>28</sup> as the graphical interface. The model was refined with ShelXL<sup>29</sup> using least squares minimization.

### 3. Results and discussion

#### 3.1. Synthesis

Owing to the metastability of many mixed anion compounds, reactions are often conducted at relatively lower temperature compared to more traditional solid state synthetic methods.<sup>3</sup> Surprisingly, however, many pentanary chalcogenides, such as the related materials ABa<sub>2</sub>MS<sub>4</sub>X (A = Na, K, Rb, Cs; M = Sn, Ge; X = Cl, Br) were able to be synthesized at ~800 °C.<sup>24,26</sup> Unfortunately, initial high-temperature syntheses targeting the title compounds at 800 °C produced a mixture of ABaTaS<sub>4</sub>, ACl, and trace crystals of the target phases A<sub>2</sub>BaTaS<sub>4</sub>Cl (A = K, Rb, Cs), suggesting metastability. To determine whether the desired phase could be isolated prior to melting, differential thermal analysis (DTA) was conducted by loading a stoichiometric reaction targeting Cs<sub>2</sub>BaTaS<sub>4</sub>Cl, as previously described. Upon heating the mixture, a significant exothermic event was observed, with an onset at 538.5 °C and a peak at 546.3 °C (Fig. S1). This suggests that synthesizing the material near this temperature may enable the formation of the desired phase

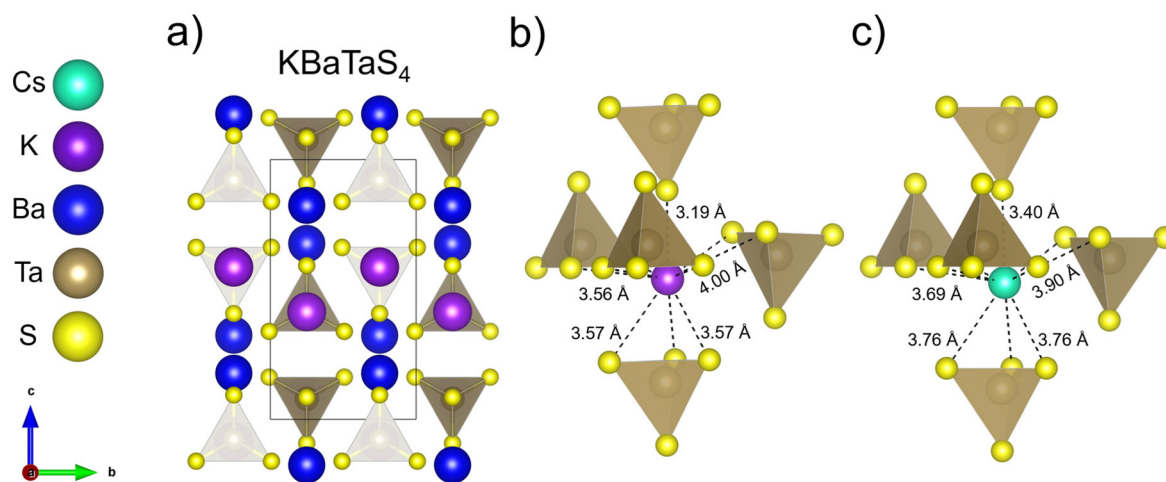
before decomposition occurs, which is presumed to take place upon melting. Synthesis at a lower temperature enabled the isolation of the target phases with only minor secondary phases; however, the resulting materials were obtained exclusively as polycrystalline powders. Additionally, bromine and iodine analogs were explored using both high temperature (800 °C) and lower temperature syntheses (500 °C); however, preliminary reactions only yielded a mixture of ABaTaS<sub>4</sub> and AX (A = K, Rb, Cs; X = Br, I).

#### 3.2. Crystal structures of KBaTaS<sub>4</sub> and CsBaTaS<sub>4</sub>

KBaTaS<sub>4</sub> and CsBaTaS<sub>4</sub> are isostructural with the previously reported RbBaTaS<sub>4</sub> and the average structure of KBaNbS<sub>4</sub>, all of which crystallize in space group *Pnma* (Fig. 2a, Fig. S2 and Table S4–7).<sup>30,31</sup> Both compounds feature isolated [TaS<sub>4</sub>]<sup>3−</sup> tetrahedra, exhibiting minor distortions, which are stacked along the *a*-axis with alternating orientations from row to row along the *b*-axis (Table S7). Additionally, each structure contains one crystallographically distinct Ba atom and one distinct alkali metal atom (K or Cs), with no evidence of site mixing.

The alkali metals (K and Cs) are each 10-coordinated, surrounded by five symmetry-related [TaS<sub>4</sub>]<sup>3−</sup> tetrahedra (Fig. 2b and c). In KBaTaS<sub>4</sub>, eight of the K–S bond lengths range from





**Fig. 2** Crystal structure of (a) KBaTaS<sub>4</sub> viewed down the *a*-axis highlighting TaS<sub>4</sub> tetrahedra, which are also found in the mixed-anion material. Moving from KBaTaS<sub>4</sub> to CsBaTaS<sub>4</sub>, there are slightly greater distortions in the (b) K<sup>+</sup> coordination environment compared to the (c) Cs<sup>+</sup> coordination environment.

3.1923(7) Å to 3.7576(19) Å, while in CsBaTaS<sub>4</sub>, the ten Cs–S bonds range from 3.4010(19) Å to 3.9046(11) Å. The remaining two K–S bonds (associated with one tetrahedron) are significantly elongated at 4.0048(17) Å each, well beyond the sum of the ionic radii for a coordination number (CN) of 10 (3.43 Å). In contrast, Ba is 9-coordinated, surrounded by six symmetry-related [TaS<sub>4</sub>]<sup>3–</sup> tetrahedra. The Ba–S bond lengths range from 3.2066(13) Å to 3.7177(5) Å in KBaTaS<sub>4</sub> and from 2.25 Å to 3.7720(6) Å in CsBaTaS<sub>4</sub>.

At room temperature, no evidence of any structural modulation was observed in any of the compounds, in contrast to the previously reported behavior in KBaNbS<sub>4</sub> where slight tilting of the NbS<sub>4</sub> tetrahedra and K and Ba displacements led to the modulation.<sup>30</sup> Additional low-temperature screening to investigate potential ordering was not conducted.

### 3.3. Crystal structures of K<sub>2</sub>BaTaS<sub>4</sub>Cl, Rb<sub>2</sub>BaTaS<sub>4</sub>Cl, and K<sub>2</sub>BaNbS<sub>4</sub>Cl

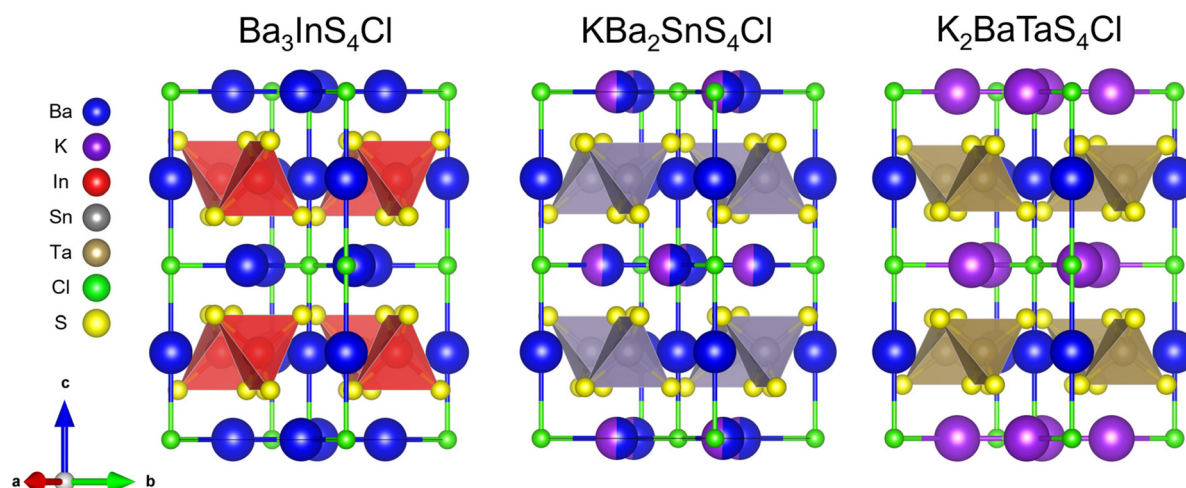
K<sub>2</sub>BaTaS<sub>4</sub>Cl, Rb<sub>2</sub>BaTaS<sub>4</sub>Cl, and K<sub>2</sub>BaNbS<sub>4</sub>Cl are isostructural with previously reported mixed-anion compounds such as NaBa<sub>2</sub>SnS<sub>4</sub>Cl, KBa<sub>2</sub>SnS<sub>4</sub>Cl, Ba<sub>3</sub>InS<sub>4</sub>Cl, and Ba<sub>3</sub>InSe<sub>4</sub>Cl, all of which adopt the Cs<sub>3</sub>CoCl<sub>5</sub> structure type.<sup>19,22,24</sup> These materials can alternatively also be described within the K<sub>3</sub>SO<sub>4</sub>F structure-type, which emphasizes the additional anion ordering present. As is the case with both the Cs<sub>3</sub>CoCl<sub>5</sub> and K<sub>3</sub>SO<sub>4</sub>F structure types, K<sub>2</sub>BaTaS<sub>4</sub>Cl, Rb<sub>2</sub>BaTaS<sub>4</sub>Cl and K<sub>2</sub>BaNbS<sub>4</sub>Cl all crystallize in the tetragonal space group, *I4/mcm*, and can be seen as the M<sup>V</sup> analogues of the previously reported mixed-anion compounds, Ba<sub>3</sub>InS<sub>4</sub>Cl and KBa<sub>2</sub>SnS<sub>4</sub>Cl (Fig. 3 and Table 1).<sup>22,24</sup> As the oxidation state of the metal increases from In<sup>III</sup> to Sn<sup>IV</sup> and ultimately to Ta<sup>V</sup>, substitution of a Ba<sup>2+</sup> cation with a monovalent alkali metal provides charge compensation for the additional positive charge, while preserving the overall structural framework with minimal distortions.

There are several ways to describe the structure of these materials. For example, Li *et al.* describe these compounds as being arranged in two layers stacked along the *c*-axis.<sup>24</sup> Using this explanation, in one layer there are 8-coordinated Ba/A (A = K, Rb) bound to Cl and S along with octahedral Cl atoms, we can call this *layer A*, followed by a layer composed of MS<sub>4</sub> tetrahedra and 10-coordinated Ba/A atoms, which we can call *layer B* (Fig. 4a). These two kinds of planes are stacked alternately to build up the complete 3-dimensional structure. Alternatively, these materials can be viewed as an ionic cage of alkali and alkaline earth metal cations surrounding MS<sub>4</sub> tetrahedron, similar to that of an anti-perovskite in the one-tilt system *a*<sup>o</sup>*a*<sup>o</sup>*c*<sup>–</sup>.<sup>32–35</sup> For the M<sup>5+</sup> case, this results in the formation of an ionic cage of octahedral, [A<sub>2</sub>BaCl]<sup>3+</sup>, connected by [MS<sub>4</sub>]<sup>3–</sup> tetrahedra, which are additionally held in place through A–S and Ba–S bonds. This explanation also helps us better understand how these mixed-anion compounds relate to their degradation products, ABaTaS<sub>4</sub> and ACl (Fig. 4b and Fig. S2).

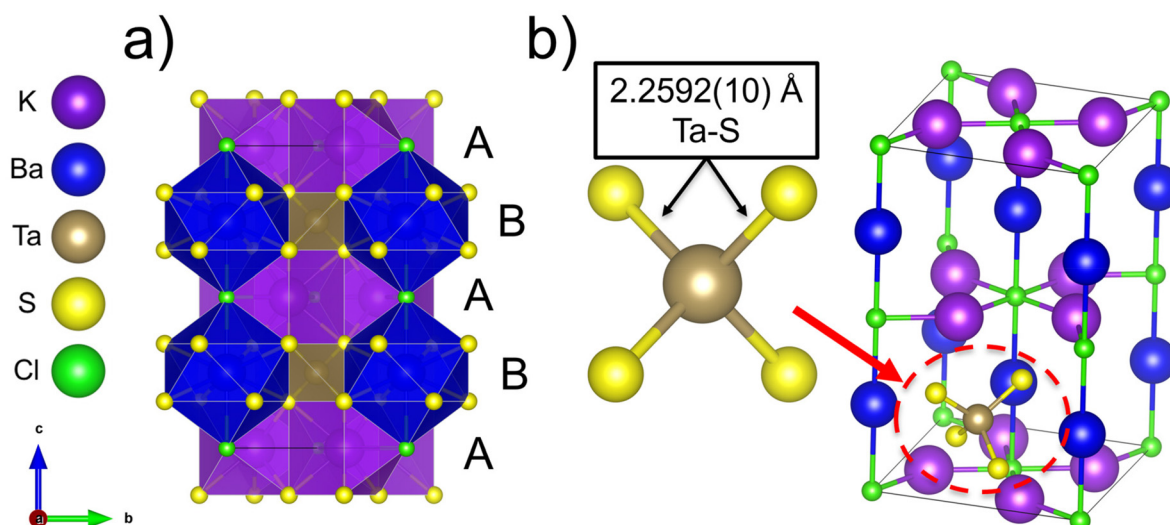
Although structurally very similar, the three compounds exhibit subtle differences in the ordering of K/Rb and Ba cations. In K<sub>2</sub>BaTaS<sub>4</sub>Cl, the alkali metal K and Ba occupy distinct Wyckoff sites and are thus crystallographically independent. In contrast, K<sub>2</sub>BaNbS<sub>4</sub>Cl and Rb<sub>2</sub>BaTaS<sub>4</sub>Cl show varying degrees of cation mixing between the alkali metal and alkali earth metal sites. While Rb<sub>2</sub>BaTaS<sub>4</sub>Cl has a constant distribution of 2/3 Rb and 1/3 Ba in both *layer A* and *layer B*, in K<sub>2</sub>BaNbS<sub>4</sub>Cl *layer B* remains Ba rich, 88% Ba and 12% K, while *layer A* remains K rich, 94% K and 6% Ba (Fig. S3). This trend shows a dependence on the size of the metal tetrahedra in relation to the degree of alkali/alkali-earth metal ordering.

Finally, a challenge in the structural refinement arises from the difficulty in distinguishing Cl<sup>–</sup> and S<sup>2–</sup> atoms crystallographically due to their similar X-ray scattering factors. To address this issue, anions assignments were guided by hard-soft acid-base theory, consistent with approaches used in





**Fig. 3** Crystal structure of  $A_x\text{Ba}_{3-x}\text{M}^{(\text{III}+x)}\text{S}_4\text{Cl}$  compounds. As the oxidation state of the metal increases from  $\text{In}^{3+}$  to  $\text{Ta}^{5+}$ , additional alkali metal cations are introduced to maintain charge balance, compensating for the higher positively charged metal. Alkali/alkali earth metal–sulfur bonds are not drawn to better distinguish the  $[\text{TaS}_4]^{3-}$  tetrahedron.



**Fig. 4** Crystal structure of  $\text{K}_2\text{BaTaS}_4\text{Cl}$  (a) down the  $a$ -axis highlighting the layered stacking sequence as well as the (b)  $[\text{K}_2\text{BaCl}]^{3+}$  ionic framework with a singular undistorted  $[\text{TaS}_4]^{3-}$  unit within the cage.

related compounds. Given that  $\text{S}^{2-}$  is a much softer acid compared to  $\text{Cl}^-$ , S was assigned to covalently bind to the Nb/Ta atoms, while Cl was assigned to exclusively bond with the harder A/Ba ( $A = \text{K}, \text{Rb}$ ), matching  $\text{Ba}_3\text{InS}_4\text{Cl}$  and  $\text{KBa}_2\text{SnS}_4\text{Cl}$ . Additionally, the tetrahedral Nb–S and Ta–S bond distances of  $\sim 2.26$  Å are identical to previously reported  $\text{NbS}_4$  and  $\text{TaS}_4$  tetrahedra *e.g.*  $\text{A}_3(\text{Nb}, \text{Ta})\text{S}_4$  ( $A = \text{K}, \text{Rb}, \text{Cs}$ ) while no tetrahedral Nb/Ta–Cl species are reported with Nb/Ta compounds primarily forming octahedra when coordinating with Cl.

### 3.4. Crystal structures of $\text{Cs}_2\text{BaTaS}_4\text{Cl}$

$\text{Cs}_2\text{BaTaS}_4\text{Cl}$  adopts a structure similar to its K and Rb analogues, however, it uniquely forms a supercell, resulting in a  $\sqrt{2}$  expansion along the  $a$ -axis and a  $2\sqrt{2}$  expansion along the

$b$ -axis. This distortion arises from preferential site ordering between  $\text{Ba}^{2+}$  and  $\text{Cs}^+$ , leading to a more pronounced rearrangement of the ionic framework than observed in any other compounds (Fig. 5, 6 and Table 1). The effect of this site preference can be most clearly seen when observing the Cl coordination environment. In the typical  $\text{Cs}_3\text{CoCl}_5$  structure, every Cl atom forms an undistorted octahedron that is corner sharing. In contrast, for  $\text{Cs}_2\text{BaTaS}_4\text{Cl}$ , the Cl atoms adopt both an undistorted octahedral coordination and a distorted one, which can be seen as alternating 2-tilt and 1-tilt regions when viewed as an anti-perovskite like structure (Fig. 7). This is caused by Cs and Ba site ordering within *layer A* of the structure, where a  $\text{Cl}^-$  anion coordinates to both a distinct Cs and Ba rather than being randomly mixed or only coordinated to



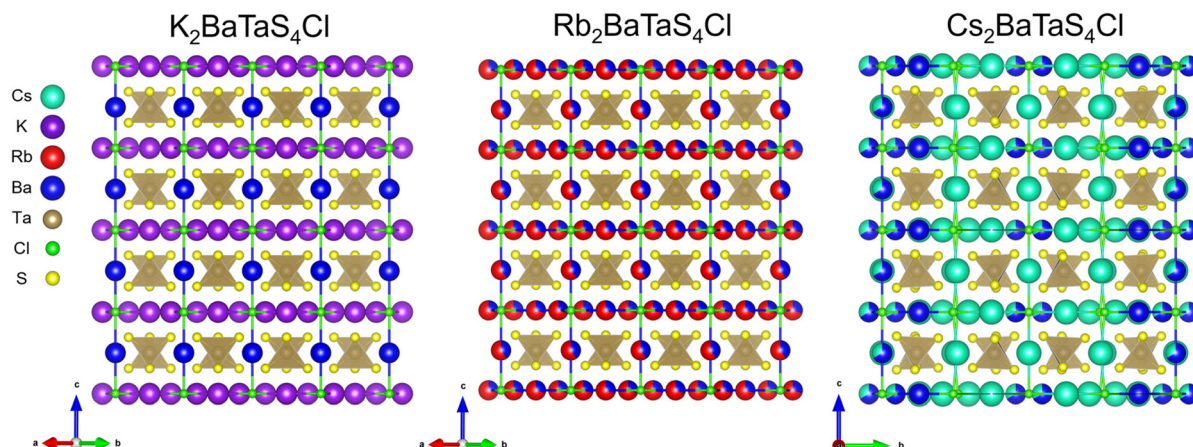


Fig. 5 Crystal structures of  $\text{K}_2\text{BaTaS}_4\text{Cl}$ ,  $\text{Rb}_2\text{BaTaS}_4\text{Cl}$ , and  $\text{Cs}_2\text{BaTaS}_4\text{Cl}$  showing additional cation mixing as the alkali metal sizes increase. Alkali/alkali earth metal–sulfur bonds not drawn to better distinguish  $\text{TaS}_4$  tetrahedron.

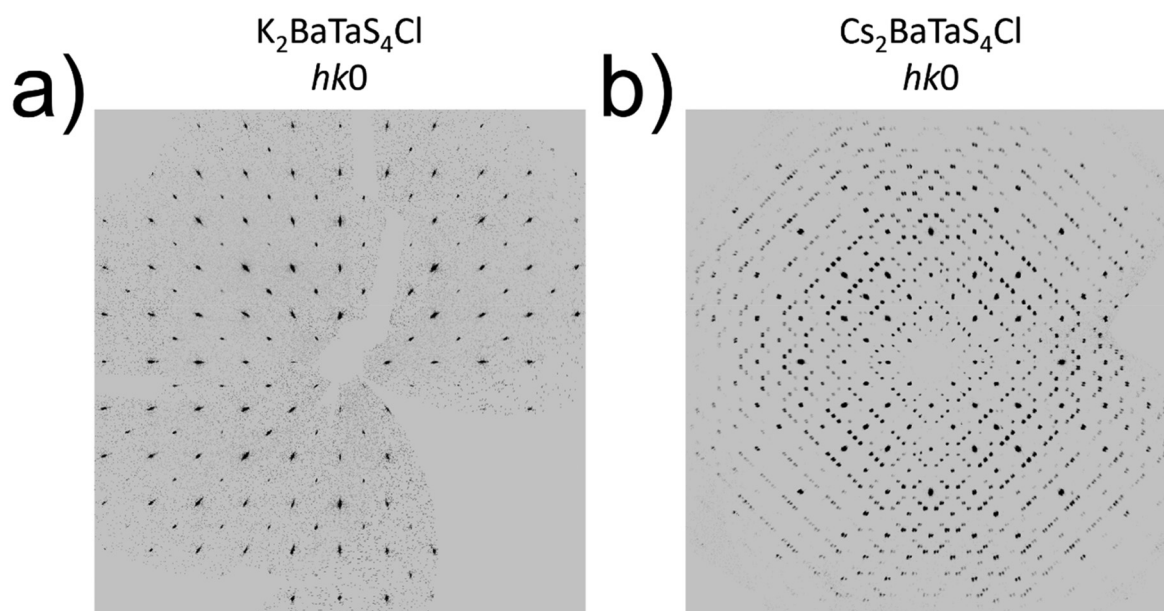


Fig. 6 Synthetic precession image of reciprocal space when viewed down the  $c$ -axis ( $hk0$  plane) for  $\text{K}_2\text{BaTaS}_4\text{Cl}$  and  $\text{Cs}_2\text{BaTaS}_4\text{Cl}$ .  $\text{Cs}_2\text{BaTaS}_4\text{Cl}$  shows additional satellite reflections along the  $a$  and  $b$  axes when compared to  $\text{K}_2\text{BaTaS}_4\text{Cl}$ , resulting in a  $\sqrt{2}$  expansion along the  $a$ -axis and a  $2\sqrt{2}$  expansion along the  $b$ -axis.

an alkali metal. As  $\text{Ba}^{2+}$  is more electronegative than  $\text{Cs}^+$ , this results in the Cs-rich octahedra becoming distorted as it is pulled towards  $\text{Ba}^{2+}$ .

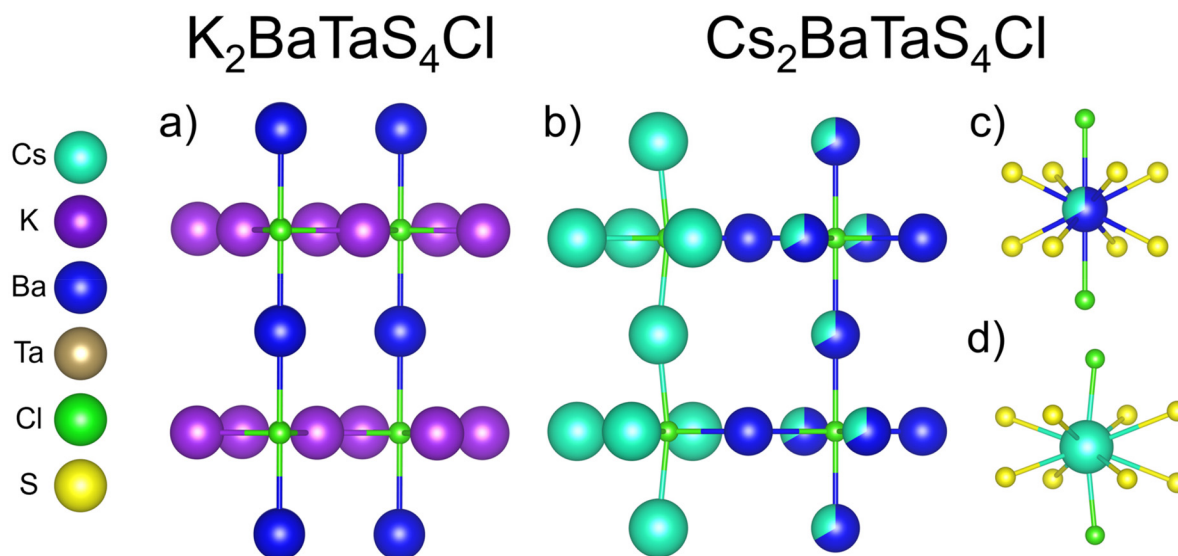
As Cs and Ba cations can be difficult to distinguish crystallographically due to their similar X-ray scattering factors, comparison of coordination environments and bond lengths were used to distinguish between the two. Thus, to determine the proper assignments for each crystallographic site, bond valence sum (BVS) analysis was used to determine which sites were Cs, which sites were Ba, and which sites were mixed (Table 2).<sup>36</sup> In conducting these calculations, it was observed that one site was deemed to be only Ba, showing a BVS of  $\sim 2$ , while four other sites were assigned only Cs as they all show a

BVS  $\sim 1$ . This left two sites that showed values between 1 and 2, independent of which element was assigned to these sites. We thus concluded that these sites were mixed occupancy, making them  $1/3$  Cs and  $2/3$  Ba to maintain charge neutrality.

### 3.5. Air stability and solubility

Air stability was measured on all samples after 3 weeks, where PXRD was monitored on samples left out in ambient conditions. It was observed that  $\text{K}_2\text{BaTaS}_4\text{Cl}$ ,  $\text{K}_2\text{BaNbS}_4\text{Cl}$ ,  $\text{Rb}_2\text{BaTaS}_4\text{Cl}$  remained stable over 1 month in ambient conditions, as no clear change in the PXRD was observed, while after a month,  $\text{Cs}_2\text{BaTaS}_4\text{Cl}$  entirely degraded (Fig. S4).





**Fig. 7** Cl coordination environments for (a)  $K_2BaTaS_4Cl$  and (b)  $Cs_2BaTaS_4Cl$  alongside (c and d) the layer A alkali metal coordination environments for  $Cs_2BaTaS_4Cl$ .  $K_2BaTaS_4Cl$  has only undistorted Cl octahedra, while  $Cs_2BaTaS_4Cl$  shows an alternating pattern of undistorted and distorted octahedra, resulting from enhanced cation ordering and structural modulation within the layers.

**Table 2** Bond valence sum (BVS) sum calculations for Cs and Ba in  $Cs_2BaTaS_4Cl$ . BVS for both Ba and Cs are shown for mixed sites

| Atom             | Bond valence sum |
|------------------|------------------|
| Ba1/Cs1          | 1.60/2.21        |
| Ba2/Cs2          | 1.71/2.35        |
| Ba3              | 2.04             |
| Cs3              | 1.14             |
| Cs4              | 1.13             |
| Cs5              | 0.94             |
| Cs6 <sup>a</sup> | 1.28 (0.80)      |

<sup>a</sup> BVS in parenthesis are calculated assuming Ba as the atom.

Additionally, the solubility of  $K_2BaTaS_4Cl$  was tested in water ( $H_2O$ ), dimethylformamide (DMF), acetonitrile (ACN), and ethanol (EtOH). In the protic solvents,  $H_2O$  and EtOH, all materials instantly degraded, which was observed with  $H_2S$  formation, resulting in bubbling and the solvent turning yellow. While the material remained stable in the aprotic solvents, DMF and ACN, significant solubility was not observed (Fig. S5).

### 3.6. Thermal stability

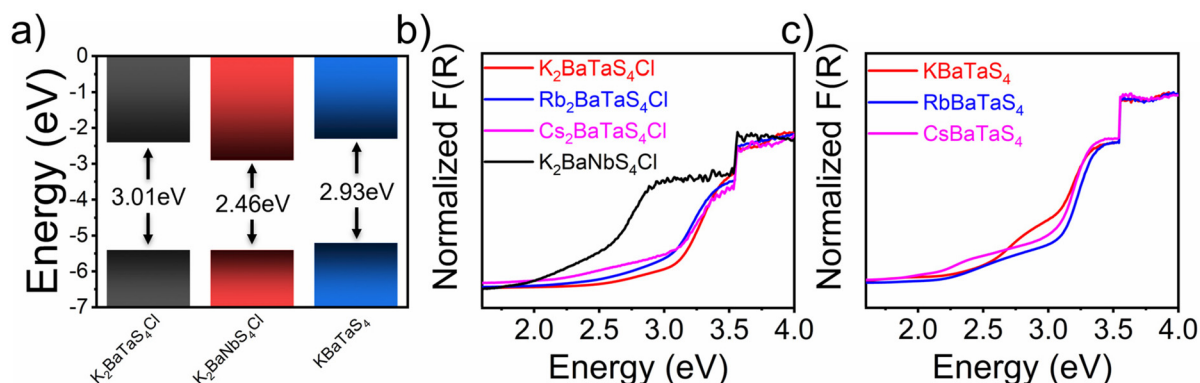
Thermal stability was investigated using differential thermal analysis (DTA) and PXRD before and after thermal cycling (DTA methods can be found in the SI). DTA revealed endothermic events presumed to correspond to melting at 680 °C, 618 °C, and 643 °C for  $K_2BaTaS_4Cl$ ,  $Rb_2BaTaS_4Cl$ , and  $K_2BaNbS_4Cl$ , respectively. Interestingly,  $Cs_2BaTaS_4Cl$  reproducibly showed two endothermic events around the point of melting at 594 °C and 647 °C on heating. Upon cooling,  $K_2BaTaS_4Cl$ ,  $Cs_2BaTaS_4Cl$ , and  $K_2BaNbS_4Cl$  all showed multiple exothermic events presumably corresponding to multiple

species recrystallizing, while  $Rb_2BaTaS_4Cl$  showed a singular event at 586 °C (Fig. S6). While the majority of related compounds in the  $A_xBa_{3-x}M^{III+x}Q_4X$  family have been found to be thermally stable, which can be deduced from the high temperature synthetic methods used to obtain each, PXRD analysis confirmed that all four  $M^V$  compounds melt and degrade to  $ABaMS_4$  and  $ACl$  products, potentially due to the high formation energy of the single anion phase,  $ABaMS_4$  (Fig. S7). The extent of decomposition additionally varies among the samples:  $K_2BaTaS_4Cl$ ,  $Rb_2BaTaS_4Cl$ , and  $K_2BaNbS_4Cl$  remain mostly intact with the addition of only a few minor impurity peaks after melting. In contrast,  $Cs_2BaTaS_4Cl$  degrades completely to  $CsBaTaS_4$  and  $CsCl$  upon melting. We understand this as a result of the increased softness of the alkali metal as it gets larger, which results in a weaker bond with the hard Cl anion. Thus, resulting in greater degradation upon heating and a lower melting temperature.

### 3.7. Optical properties

Diffuse reflectance (DR) UV-Vis spectroscopy was conducted on all materials post-washing to measure each material's bandgap (Diffuse reflectance UV-Vis spectroscopy methods can be found in the SI). For the Ta based mixed-anion materials, DR UV-Vis showed bandgaps of 3.01(5) eV, 2.97(5) eV, and 2.97(5) eV for  $K_2BaTaS_4Cl$ ,  $Rb_2BaTaS_4Cl$ , and  $Cs_2BaTaS_4Cl$ , showing them all to be within error of each other and consistent with their white color. Upon replacing Ta with Nb in  $K_2BaNbS_4Cl$ , the bandgap then subsequently decreases to 2.46 (5) eV, which matches the material's bright yellow color (Fig. 8b). Upon removing an equivalent of  $ACl$  yielding  $ABaTaS_4$ , the bandgap essentially remains unchanged, showing bandgaps of 2.93(5) eV, 3.00(5) eV and 2.99(5) eV for  $KBaTaS_4$ ,  $RbBaTaS_4$ , and  $CsBaTaS_4$ , respectively, which are





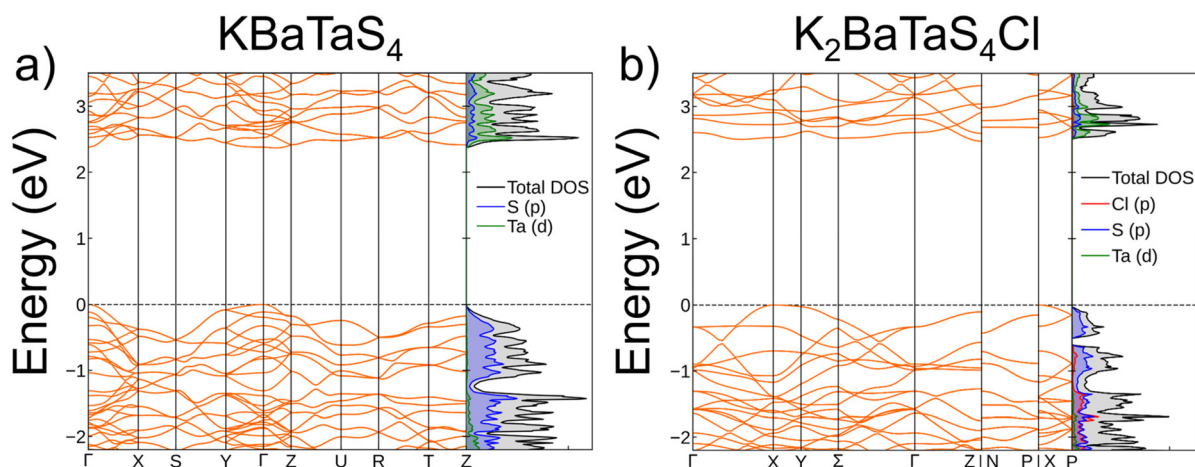
**Fig. 8** (a) Position of the CBM and VBM relative to the free electron comparing  $\text{K}_2\text{BaTaS}_4\text{Cl}$ ,  $\text{K}_2\text{BaNbS}_4\text{Cl}$  and  $\text{KBaTaS}_4$ , and the optical diffuse reflectance spectra of (b)  $\text{A}_2\text{BaMS}_4\text{Cl}$  and (c)  $\text{ABaTaS}_4$  ( $\text{A} = \text{K}, \text{Rb}, \text{Cs}$ ;  $\text{M} = \text{Nb}, \text{Ta}$ ) highlighting the extrapolated band edges. The abrupt increase in  $F(R)$  at  $\sim 3.55$  eV is an artifact from the instrument caused by a change in the detector.

within the error of the measurement with their respective mixed-anion materials (Fig. 8c). This observation is surprising, the incorporation of halide species often results in an increase in the band gap of heteroanionic materials as is the case in the related Sn compounds  $\text{Ba}_2\text{SnSe}_4$  and  $\text{KBa}_2\text{SnSe}_4\text{Cl}$ , which show a  $\sim 0.6$  eV increase in the band gap upon the incorporation of KCl.<sup>25</sup> The minimal change in the optical properties for either structure type suggests the HOMO and LUMO are dominated by sulfur and Ta/Nb states with minimal to no influence from the alkali metal and Cl states.

A better understanding of the electronic structures can be obtained by using photoemission yield spectroscopy in air (PYSA) to determine each material's first ionization energy (PYSA methods can be found in the SI). Combining bandgap measurements alongside measured ionization energies allows us to elucidate each material's conduction band minimum (CBM) and valence band maximum (VBM) relative to the energy of a free electron by subtracting the bandgap from the ionization energy (Fig. S8, 9 and Fig. 8a). This shows that all the chalcogenide materials have similar VBMs while the single

anion materials have a VBM shifted to higher energy with respect to their mixed-anion counterparts. As the  $\text{K}_2\text{BaNbS}_4\text{Cl}$  has a lower bandgap than the Ta based materials while also having an identical VBM, we can conclude that the smaller bandgap is due to a lowering of the CBM (Fig. 8a), which is governed by the Nb/Ta d orbitals at the CBM.

These findings are all corroborated with DFT-calculated band structures comparing  $\text{K}_2\text{BaTaS}_4\text{Cl}$  to  $\text{KBaTaS}_4$  (Fig. 9). The projected density of states (pDOS) reveals in both compounds the dominance of S (p) states at the Fermi level, with the empty Ta (d) orbitals forming the first conduction band, consistent with experiment. Additionally, our simulations indicate that the mixed-anion compound has a slight increase of 0.26 eV in the bandgap, 2.43 eV for  $\text{KBaTaS}_4$  compared to 2.69 eV for  $\text{K}_2\text{BaTaS}_4\text{Cl}$ . The calculations additionally show that  $\text{KBaTaS}_4$  has a direct bandgap with both the VBM and CBM located at  $\Gamma$ . In contrast, the mixed-anion compound  $\text{K}_2\text{BaTaS}_4\text{Cl}$  exhibits a significant change in electronic structure, displaying an indirect bandgap with the VBM at X and the CBM at Z.



**Fig. 9** Combined DFT electronic band structures and density of states (DOS) for (a)  $\text{KBaTaS}_4$  and (b)  $\text{K}_2\text{BaTaS}_4\text{Cl}$ .



## 4. Conclusions

The discovery of novel mixed-anion materials remains a significant challenge, largely due to the thermodynamic preference for forming more stable single-anion phases. By building on prior work with compounds of the formula  $A_xBa_{3-x}M^{III+x}Q_4X$ , and employing low-temperature synthesis, we successfully prepared four novel chalcogenides,  $K_2BaTaS_4Cl$ ,  $Rb_2BaTaS_4Cl$ ,  $Cs_2BaTaS_4Cl$  and  $K_2BaNbS_4Cl$ , by incorporating a pentavalent transition metal. These results demonstrate that the A/Ba ratio in this structural family can be tuned to accommodate higher metal oxidation states. We further show that alkali metal size significantly impacts cation ordering, with increasing size leading to greater A/Ba mixing culminating in the emergence of a superstructure for  $Cs_2BaTaS_4Cl$ . Despite these structural variations, the electronic properties remain largely unchanged across the series, with the valence and conduction band edges dominated by chalcogen and transition metal states, as supported by DFT, experimental band gaps, and PYSA measurements. Together, these findings underscore how subtle changes in composition and size affect structure in these mixed-anion phases, while offering a framework for designing new mixed-anion materials.

## Conflicts of interest

The authors declare no competing financial interest.

## Data availability

Crystallographic tables and other data supporting this article are also provided in the SI: additional experimental details and methods, DTA reaction of  $Cs_2BaTaS_4Cl$ , crystal structure figure of  $CsBaTaS_4$  and  $K_2BaNbS_4Cl$ , air stability and solvent stability tests, DTA graphs of  $K_2BaTaS_4Cl$ ,  $Rb_2BaTaS_4Cl$ ,  $Cs_2BaTaS_4Cl$ , and  $K_2BaNbS_4Cl$  as well as their PXRDs before and after heating, PYSA graphs, and additional crystallographic tables for all the reported compounds. See DOI: <https://doi.org/10.1039/d5dt01676b>.

CCDC 2472244–2472250 contain the supplementary crystallographic data for this paper.<sup>37a–g</sup>

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